Amendments to the Abstract:

A microwave plasma processing method and, in which a linear plasma is produced by means of a microwave, the surface of an object to be processed is held horizontally with respect to the linear plasma, and the an object is to be processed is subjected to processing under the atmospheric pressure or under a pressure near the atmospheric pressure while when the object is being moved, a microwave plasma processing apparatus and its plasma head are disclosed. The while a surface of the object is maintained at a horizontal position with respect to the linear plasma. A plasma head has an H-plane slot antenna, and slots are made in the slot antenna at a pitch of λg/2 in zigzag manner arranged alternately on both sides of the a centerline of the a waveguide at a pitch of λg/2 (λg: wavelength of the microwave with the waveguide). The distance from the slots to the emission end of the plasma head is set to n · λg/2 (λg is the wavelength in the tube of the microwave). The plasma-head further has an E-plane slot antenna, and slots are made in the slot antenna at a pitch of λg along the centerline of the waveguide. A uniforming line having a distance of n· λg/2 from the slots to the an emission end of the plasma head is disposed provided (n: an integral number).